

## Supporting Information for

### Designing Thiophene-fused benzoxadizole as an Acceptor to Build a Narrow Bandgap Polymer for All-Polymer Solar Cells

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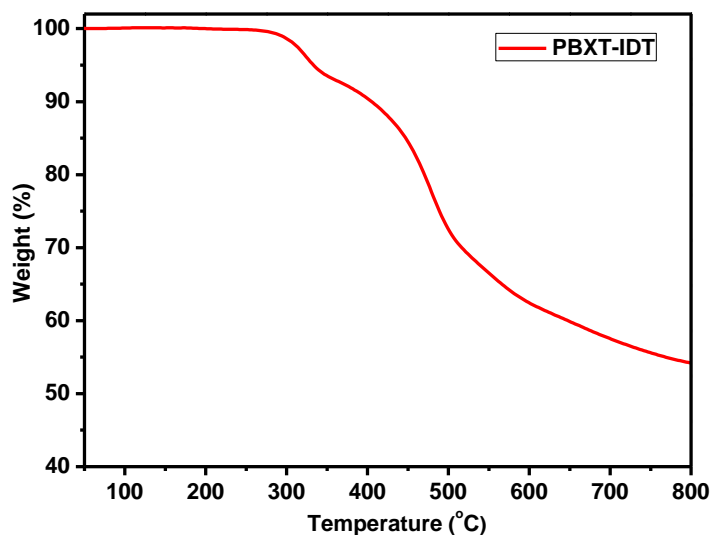
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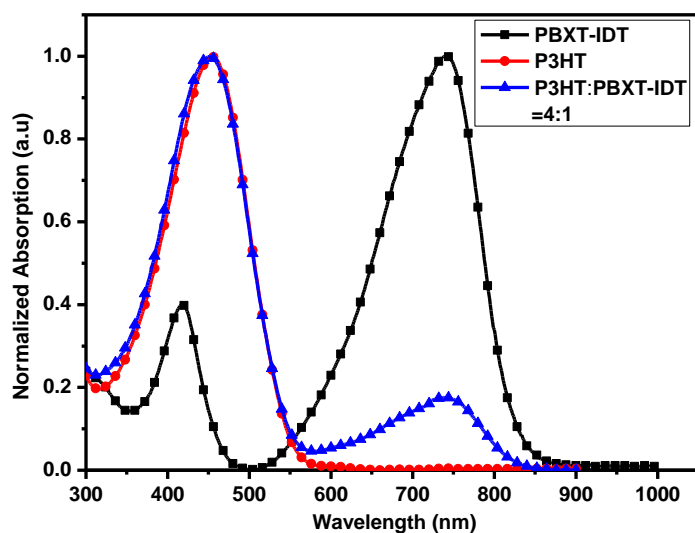
#### Device fabrication

All polymer solar cells were fabricated with a structure of ITO/PEDOT:PSS/P3HT:PBXT-IDT/Ca/Al. The patterned indium tin oxide (ITO) glass (sheet resistance =  $10 \Omega \square^{-1}$ ) was pre-cleaned in an ultrasonic bath of deionized water, acetone and isopropanol, followed by oxygen plasma treatment (25 min) in an ultraviolet–ozone chamber (Jelight Company, USA). A thin layer (30 nm) of poly(3,4-ethylenedioxythiophene):poly(styrene sulfonate) (PEDOT:PSS, Baytron PVP Al 4083, Germany) was spin-coated onto the ITO glass at 4000 rpm and baked subsequently at 150 °C for 20 min. The mixture of P3HT:PBXT-IDT in chlorobenzene solvent (14 mg mL<sup>-1</sup> in total) with or without chloroform was spin-coated on a PEDOT:PSS layer to form an active layer. Calcium (ca. 20 nm) and aluminium (ca. 80 nm) layers were deposited onto the active layer in a vacuum at a pressure of ca.  $5.0 \times 10^{-5}$  Pa to form the negative electrode. The active area of the device was 4 mm<sup>2</sup>. The current density–voltage (*J*-*V*) characteristics were measured on a computer–controlled B2912A Precision Source/Measure Unit (Agilent Technologies). A XES-70S1 (SAN-EI Electric Co., Ltd) solar simulator (AAA grade, 70 × 70 mm<sup>2</sup> photobeam size) coupled with AM 1.5 G solar spectrum filters was used as the light

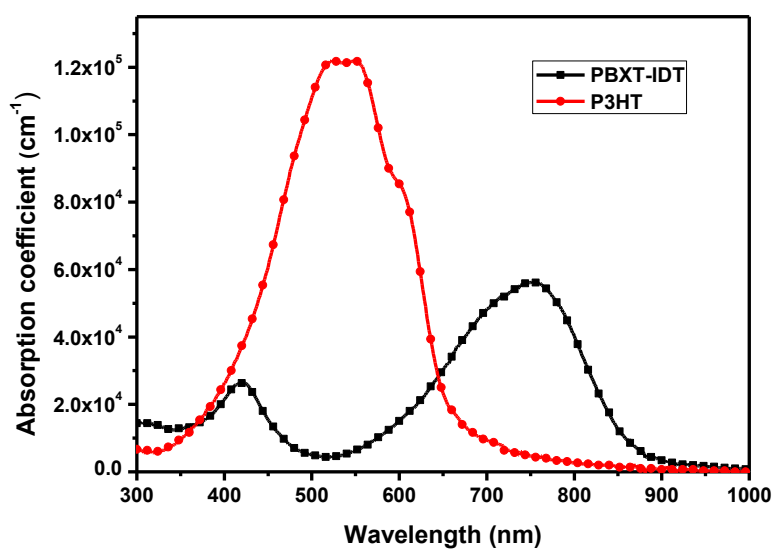
source, and the optical power at the sample was  $100 \text{ mW/cm}^2$ . A  $2 \times 2 \text{ cm}^2$  monocrystalline silicon reference cell (SRC-1000-TC-QZ) was purchased from VLSI Standards Inc. A Solar Cell Spectral Measurement System QE-R3011 (Enlitech Co., Ltd) was used for the EQE spectrum measurement. The light intensity at each wavelength was calibrated using a standard single crystal Si photovoltaic cell. The hole mobility and electron mobility were measured using the structure: ITO/PEDOT:PSS/P3HT:PBXT-IDT/Au and ITO/titanium (diisopropoxide) bis(2,4-pentanedionate) (TIPD)/P3HT:PBXT-IDT/Al respectively. And the mobility was extracted by fitting the current J–V curves using the Mott–Gurney relationship (space charge limited current).



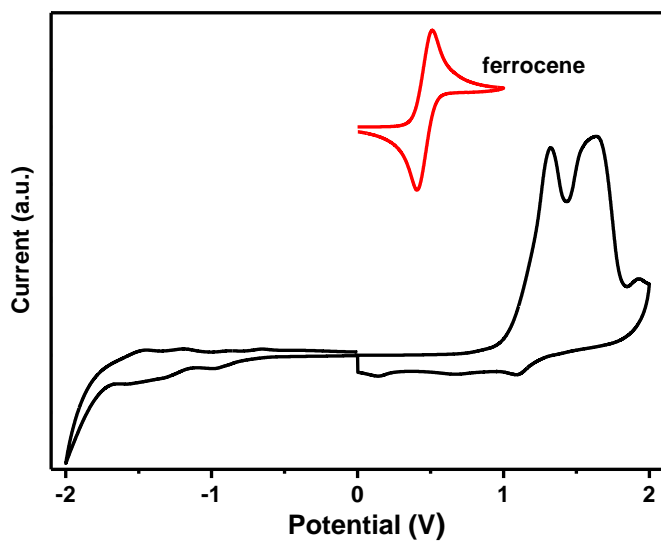
**Figure S1.** The TGA curve of PBXT-IDT



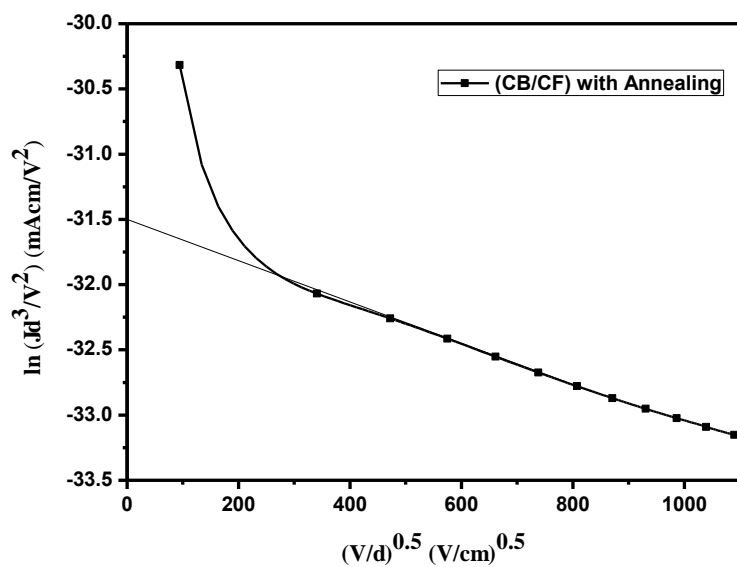
**Figure S2.** Absorption spectra of PBXT-IDT, P3HT and P3HT:PBXT-IDT (4:1,p/n) in chlorobenzene



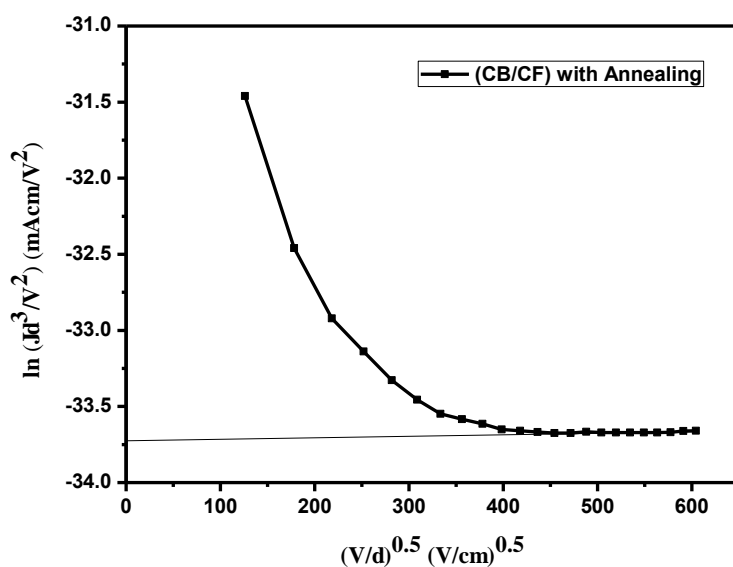
**Figure S3.** The absorption spectra of PBXT-IDT and P3HT in thin films



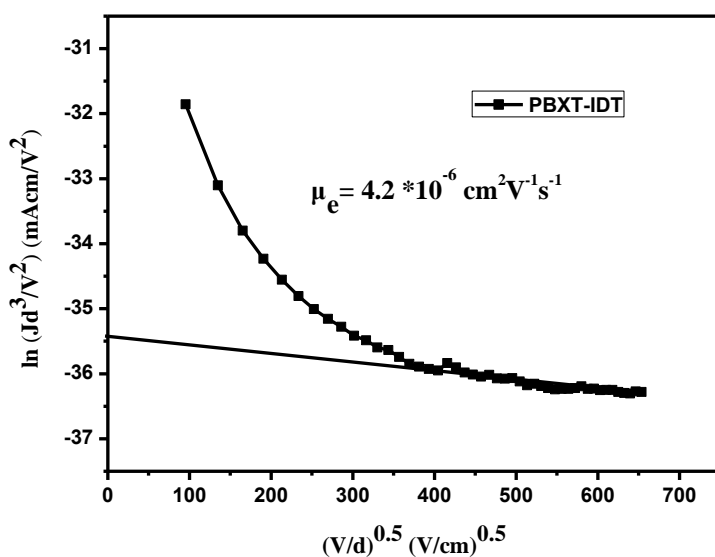
**Figure S4.** The CV curve of PBXT-IDT



**Figure S5.**  $\ln(JL^3/V^2)$  vs  $(V/L)^{0.5}$  of plot of the all-PSCs based on P3HT / PBXT-IDT for the hole mobility measurement.



**Figure S6.**  $\ln(JL^3/V^2)$  vs  $(V/L)^{0.5}$  of plot of the all-PSCs based on P3HT / PBXT-IDT for the electron mobility measurement.



**Figure S7.**  $\ln(JL^3/V^2)$  vs  $(V/L)^{0.5}$  of plot of the pure PBXT-IDT film for the electron mobility measurement.

**Table S1.** OPV performances based on PBXT-IDT and P3HT with different p/n ratio.

Polymer	p/n	$V_{oc}$ (V)	$J_{sc}$ ( mA cm <sup>-2</sup> )	FF (%)	PCE (%)
PBXT-IDT	1:1	0.83	1.15	33.59	0.32
PBXT-IDT	2:1	0.86	1.07	45.09	0.42
PBXT-IDT	3:1	0.88	1.18	44.29	0.46
PBXT-IDT	4:1	0.88	1.41	43.81	0.54
PBXT-IDT	5:1	0.83	1.19	37.01	0.36

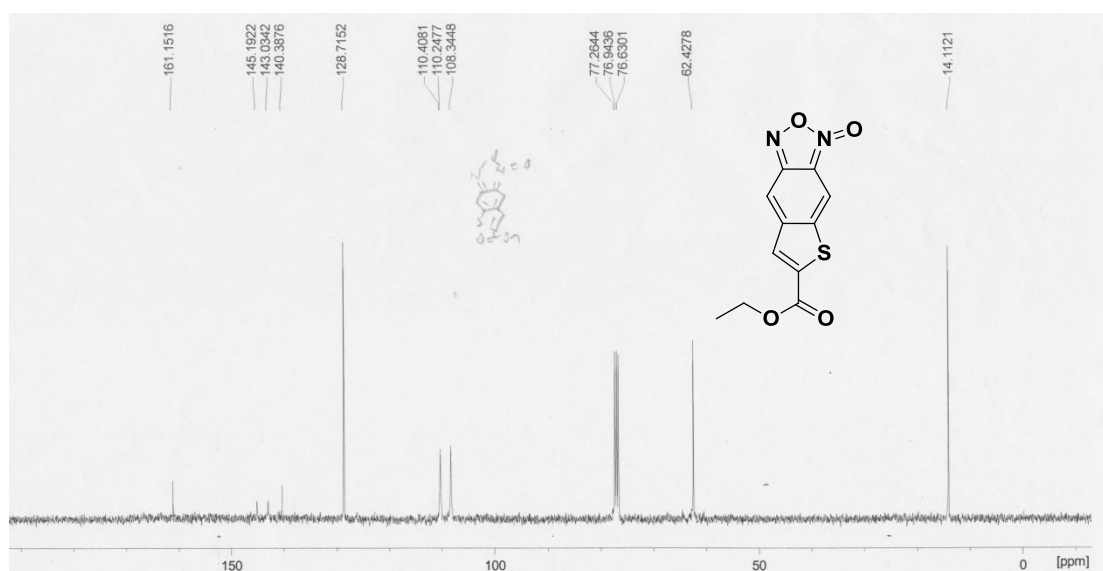
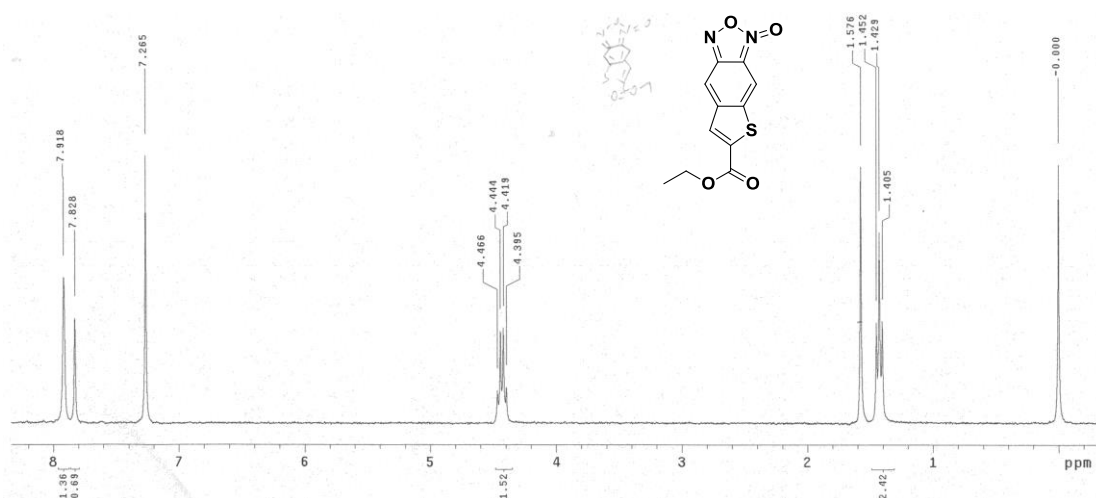
**Table S2.** OPV performances based on P3HT/PBXT-IDT (4:1, w/w) at different thermal annealing temperature.

Polymer	Annealing (°C)	$V_{oc}$ (V)	$J_{sc}$ ( mA cm <sup>-2</sup> )	FF (%)	PCE (%)
PBXT-IDT	90	0.83	2.27	40.22	0.76
PBXT-IDT	100	0.79	2.24	47.75	0.85
PBXT-IDT	110	0.76	2.15	41.30	0.68

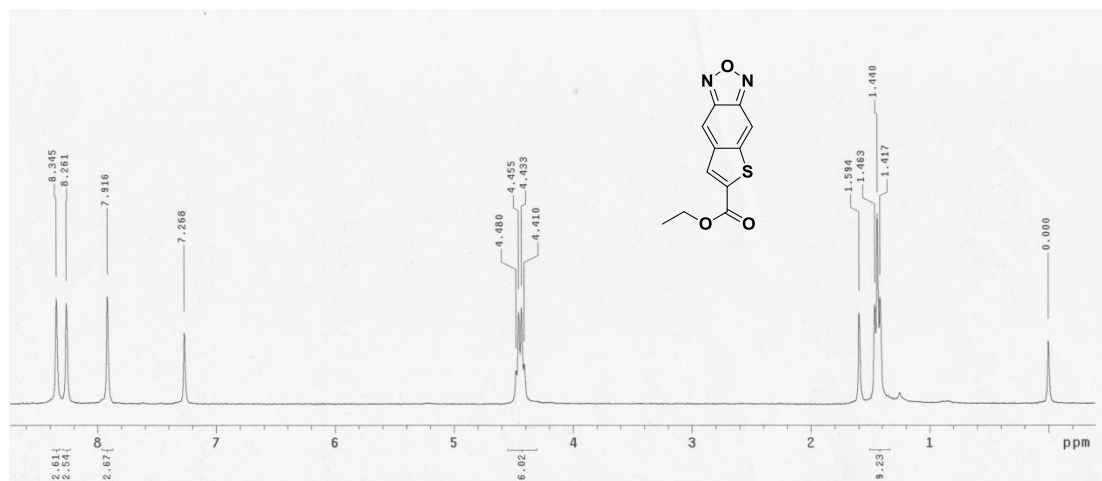
**Table S3.** OPV performances based on P3HT/PBXT-IDT (4:1, w/w) with different volume of chloroform with thermal annealing at 100 °C.

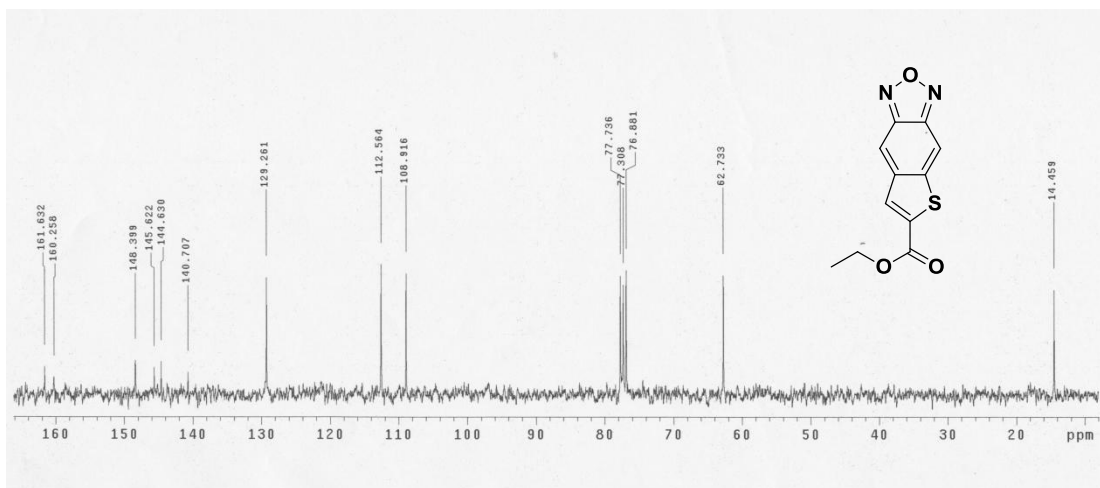
Polymer	Chloroform (%)	$V_{oc}$ (V)	$J_{sc}$ ( mA cm <sup>-2</sup> )	FF (%)	PCE (%)
PBXT-IDT	5	0.82	2.41	44.27	0.87
PBXT-IDT	10	0.84	2.95	43.86	1.09
PBXT-IDT	20	0.83	2.26	47.74	0.90

### $^1\text{H}$ NMR and $^{13}\text{C}$ NMR spectra of compound 3

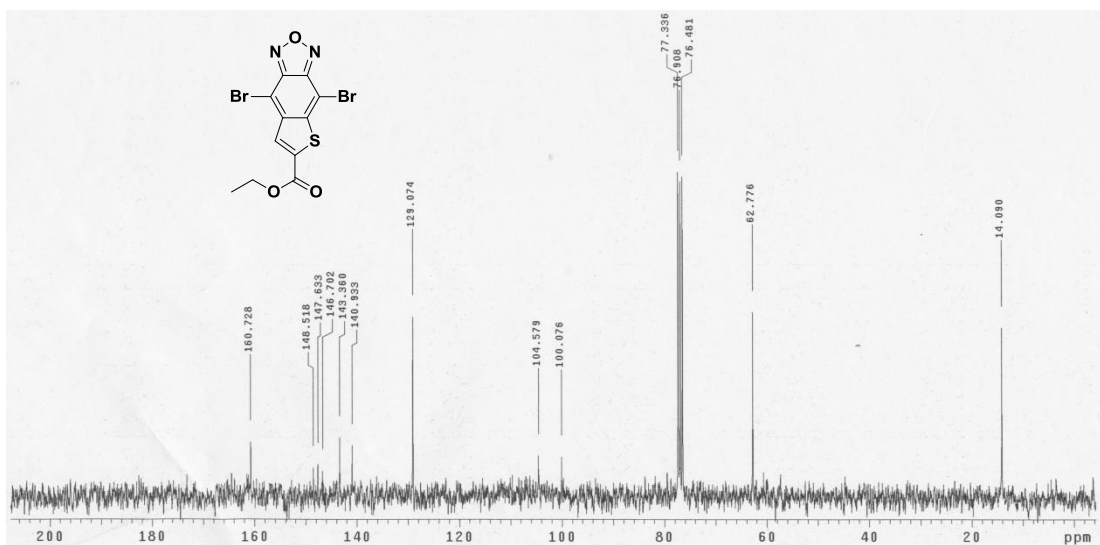
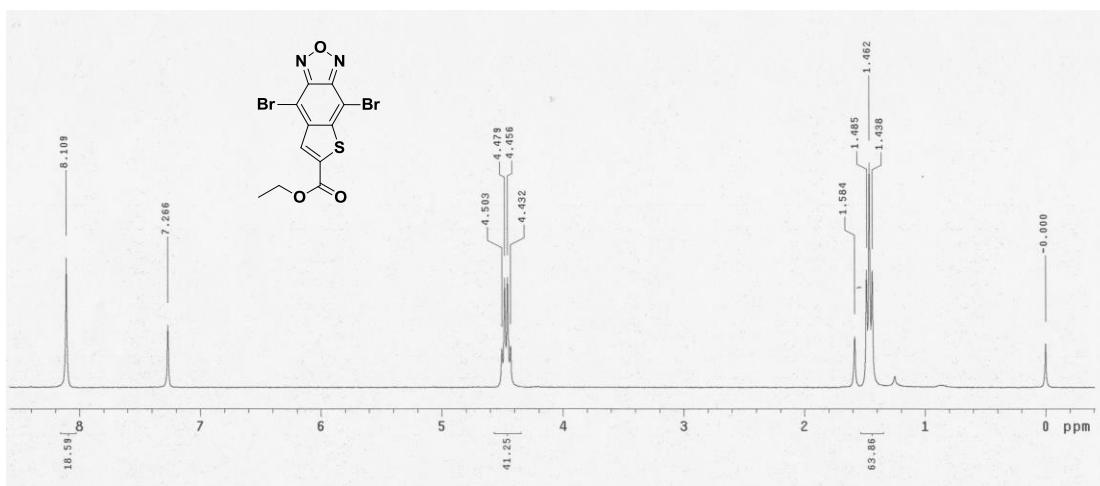


### $^1\text{H}$ NMR and $^{13}\text{C}$ NMR spectra of BXT





**<sup>1</sup>H NMR and <sup>13</sup>C NMR spectra of di-Br-BXT**





# $^1\text{H}$ NMR and $^{13}\text{C}$ NMR spectra of polymer PBXT-IDT

